

# MSKSEMI 美森科

SEMICONDUCTOR



ESD



TVS



TSS



MOV



GDT



PLED

## S9015-MS

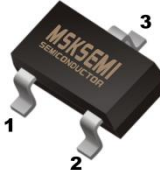

Product specification

TRANSISTOR (PNP)

**FEATURES**

- Complementary to S9014-MS

**Reference News**

PACKAGE OUTLINE	MARKING
 <p>1. BASE 2. EMITTER 3. COLLECTOR</p>	
SOT-23	

**MAXIMUM RATINGS (Ta=25°C unless otherwise noted)**

Symbol	Parameter	Value	Unit
V <sub>CB0</sub>	Collector-Base Voltage	-50	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-45	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>c</sub>	Collector Current -Continuous	-0.1	A
P <sub>c</sub>	Collector Power Dissipation	0.2	W
T <sub>j</sub>	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55-150	°C

**ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)**

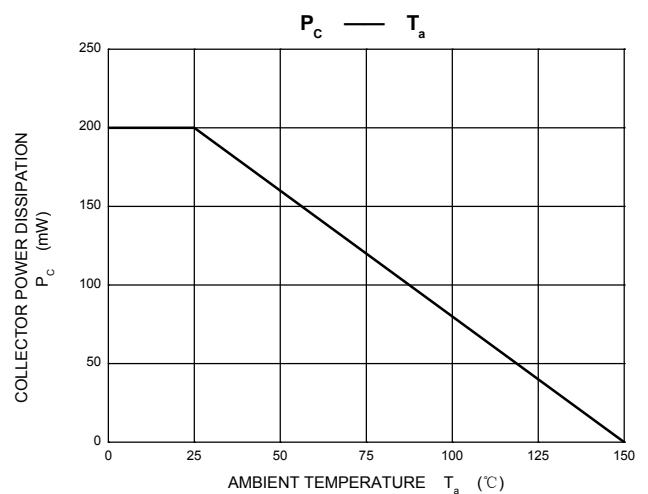
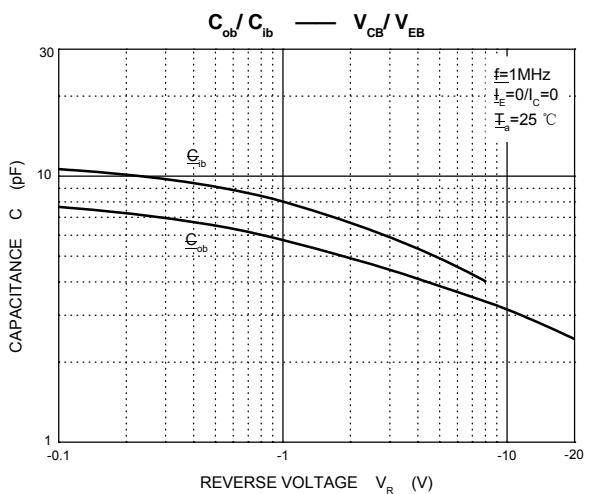
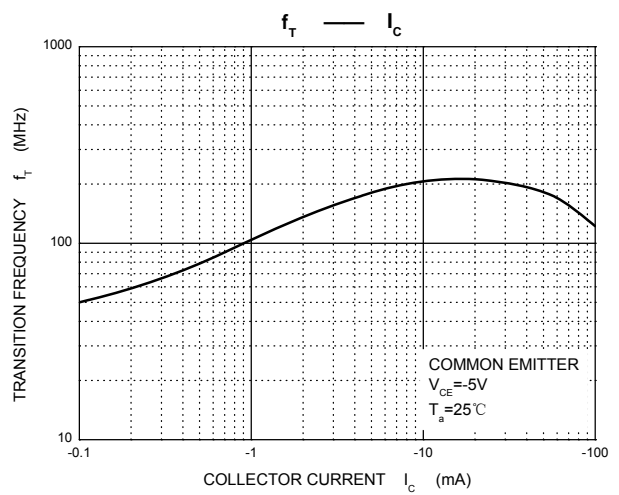
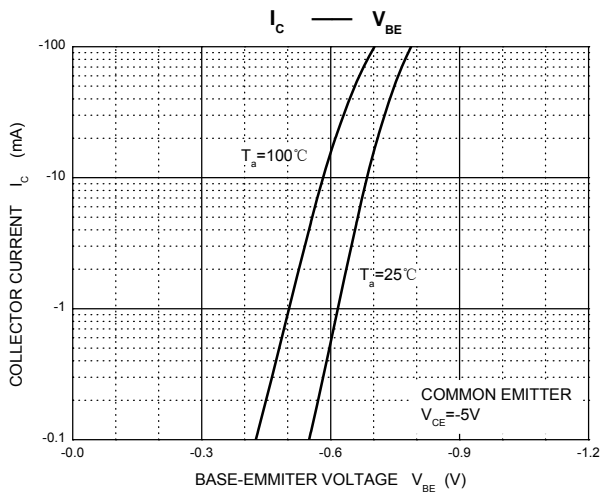
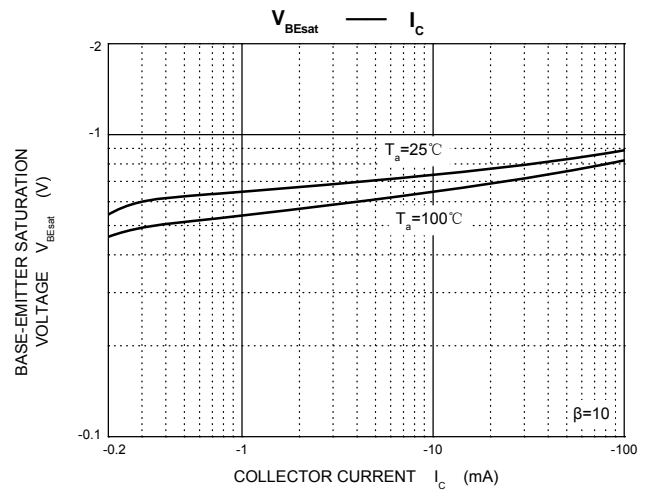
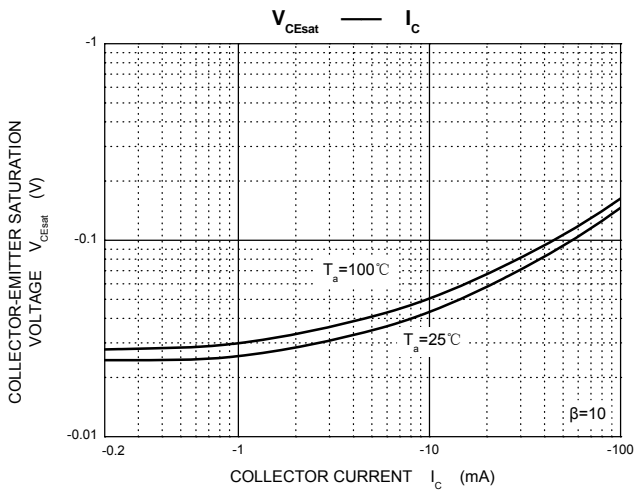
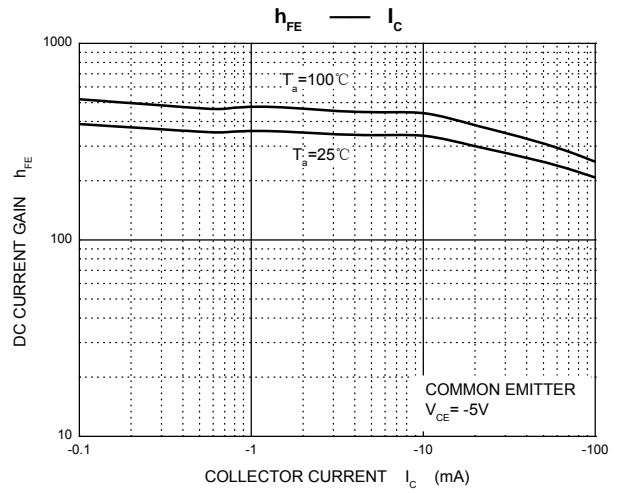
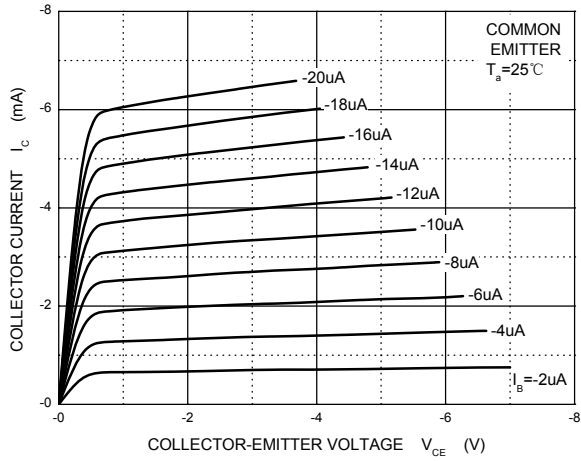
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>c</sub> = -100μA, I <sub>E</sub> = 0	-50			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>c</sub> = -0.1mA, I <sub>B</sub> = 0	-45			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> = -100μA, I <sub>C</sub> = 0	-5			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -50 V, I <sub>E</sub> = 0			-0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -5V, I <sub>C</sub> = 0			-0.1	μA
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> = -5V, I <sub>c</sub> = -1mA	200		1000	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>c</sub> = -100mA, I <sub>B</sub> = -10mA			-0.3	V
Base-emitter saturation voltage	V <sub>BE(sat)</sub>	I <sub>c</sub> = -100mA, I <sub>B</sub> = -10mA			-1	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = -5V, I <sub>c</sub> = -10mA f = 30MHz	150			MHz

**CLASSIFICATION OF h<sub>FE(1)</sub>**

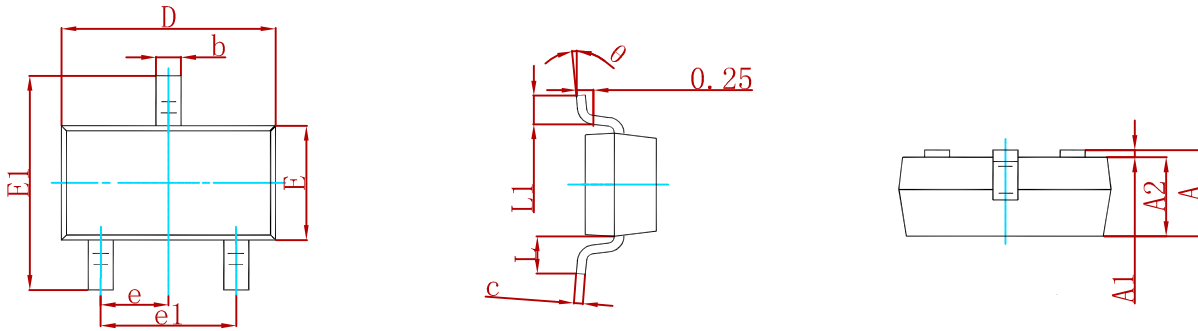
Rank	L	H
Range	200-450	450-1000

**Typical Characteristics**

**Static Characteristic**

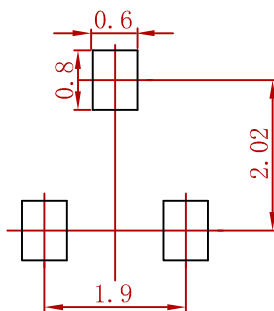


**PACKAGE MECHANICAL DATA**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

**Suggested Pad Layout**



Note:  
 1. Controlling dimension: in millimeters.  
 2. General tolerance: ± 0.05mm.  
 3. The pad layout is for reference purposes only.

**REEL SPECIFICATION**

P/N	PKG	QTY
S9015-MS	SOT-23	3000

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